

100 V, N-channel Trench MOSFET

11 April 2019

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic-level compatible
- Extended temperature range T_i = 175 °C
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM (class H2)
- AEC-Q101 qualified

3. Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	100	V
V _{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	-	1.1	А
Static chara	octeristics		•				
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 1.1 A; T _j = 25 °C		-	285	385	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



5. Pinning information

Table 2. F	Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	G	gate	3	D				
2	S	source						
3	D	drain	1 2 TO-236AB (SOT23)	G G S 017aaa255				

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PMV280ENEA	TO-236AB	plastic surface-mounted package; 3 leads	SOT23			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PMV280ENEA	EL%

[1] % = placeholder for manufacturing site code

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8. Limiting values

Table 5. Limiting values

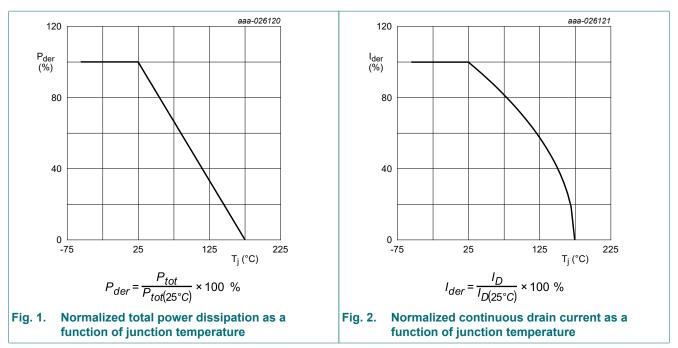
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	100	V
V _{GS}	gate-source voltage	-		-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	1.1	А
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	0.8	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	5	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	700	mW
			[1]	-	1.4	W
		T _{sp} = 25 °C		-	6	W
Tj	junction temperature			-55	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C
Source-drai	n diode	1		I		
Is	source current	T _{amb} = 25 °C	[1]	-	1.1	А
ESD maxim	um rating			I		
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	2000	V
Avalanche r	uggedness	,		I	1	
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	T _{j(init)} = 25 °C; I _D = 0.16 A; DUT in avalanche (unclamped)		-	8.4	mJ
	I	1				

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[3] Measured between all pins.

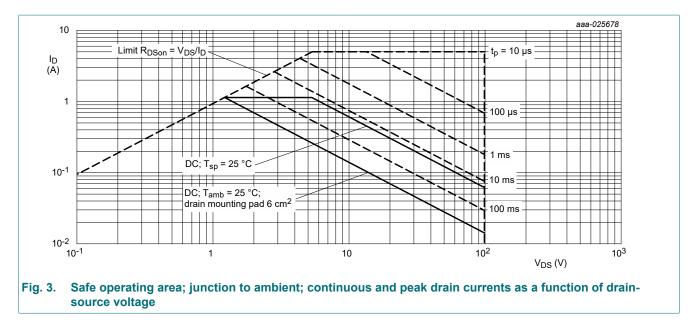


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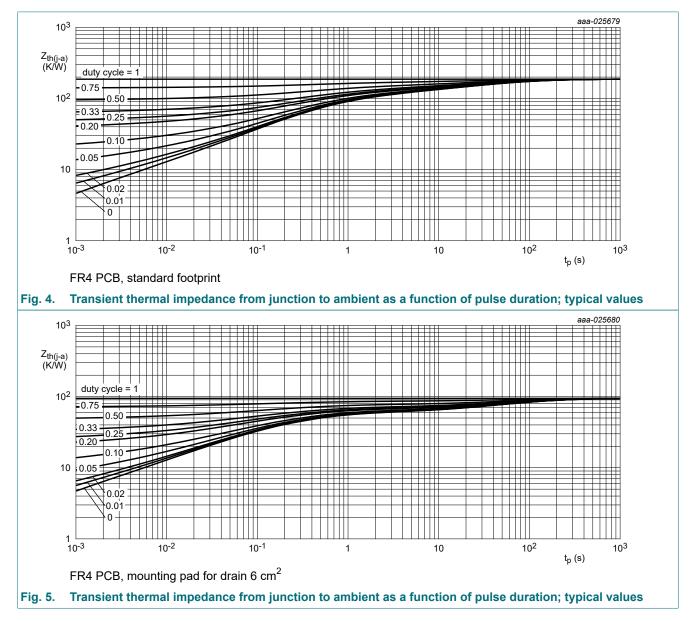
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9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	186	215	K/W
	junction to ambient		[2]	-	96	110	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	20	25	K/W

Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint. [1]

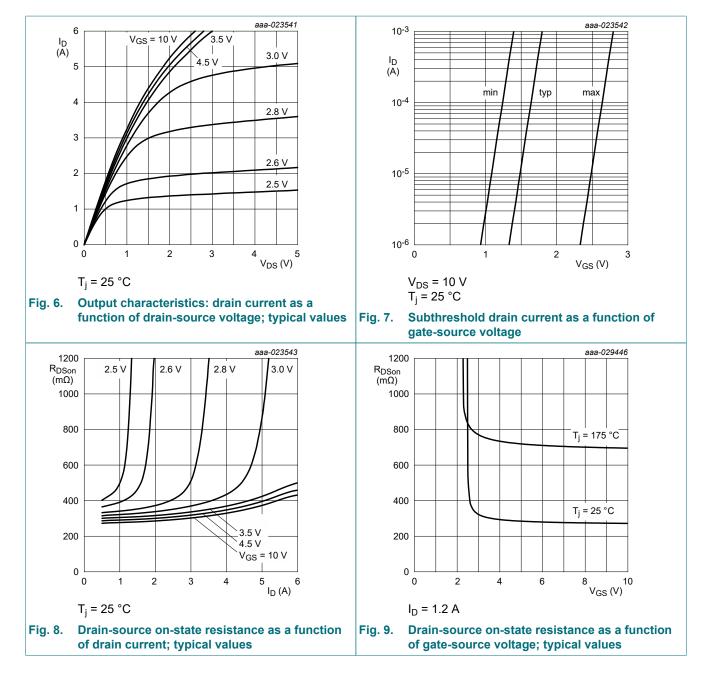
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



10. Characteristics

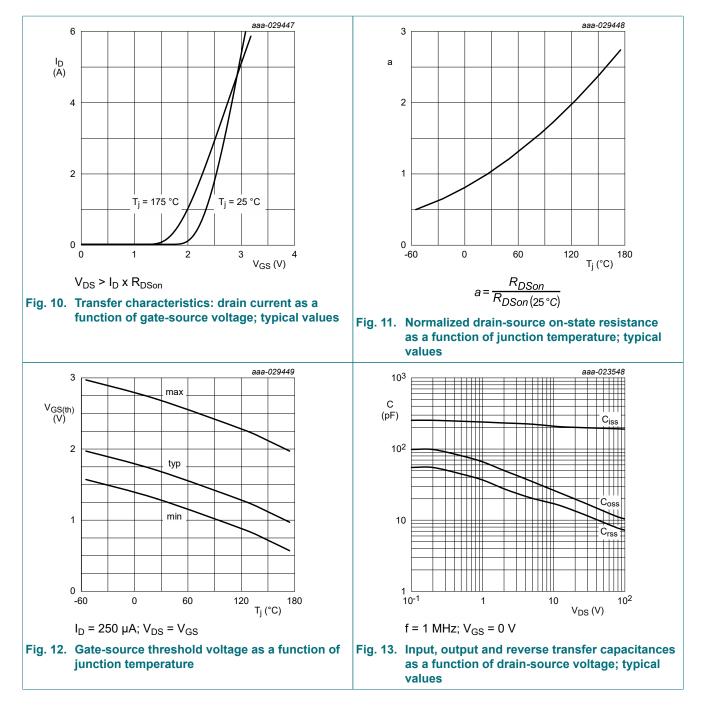
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	100	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = 250 μA; V _{DS} =V _{GS} ; T _j = 25 °C	1.3	1.7	2.7	V
I _{DSS}	drain leakage current	V _{DS} = 100 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	15	μA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-15	μA
		V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-1	μA
R _{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 1.1 A; T _j = 25 °C	-	285	385	mΩ
	resistance	V _{GS} = 10 V; I _D = 1.1 A; T _j = 175 °C	-	798	1078	mΩ
		V _{GS} = 4.5 V; I _D = 1.1 A; T _j = 25 °C	-	301	432	mΩ
9fs	forward transconductance	V _{DS} = 10 V; I _D = 1.1 A; T _j = 25 °C	-	5.2	-	S
R _G	gate resistance	f = 1 MHz	-	1.8	-	Ω
Dynamic ch	aracteristics		I			
Q _{G(tot)}	total gate charge	V _{DS} = 50 V; I _D = 1.1 A; V _{GS} = 10 V;	-	4.5	6.8	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.5	-	nC
Q _{GD}	gate-drain charge		-	1.1	-	nC
C _{iss}	input capacitance	V _{DS} = 50 V; f = 1 MHz; V _{GS} = 0 V;	-	190	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	13	-	pF
C _{rss}	reverse transfer capacitance		-	9	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = 50 V; I _D = 1.1 A; V _{GS} = 10 V;	-	3	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	4	-	ns
t _{d(off)}	turn-off delay time		-	10	-	ns
t _f	fall time		-	3	-	ns
Source-drai	n diode	· · ·				
V _{SD}	source-drain voltage	I _S = 1.1 A; V _{GS} = 0 V; T _j = 25 °C	-	0.8	1.2	V
t _{rr}	reverse recovery time	I _S = 1.1 A; dI _S /dt = -100 A/µs;	-	20	-	ns
Q _r	recovered charge	V _{GS} = 0 V; V _{DS} = 40 V; T _j = 25 °C	-	11	-	nC

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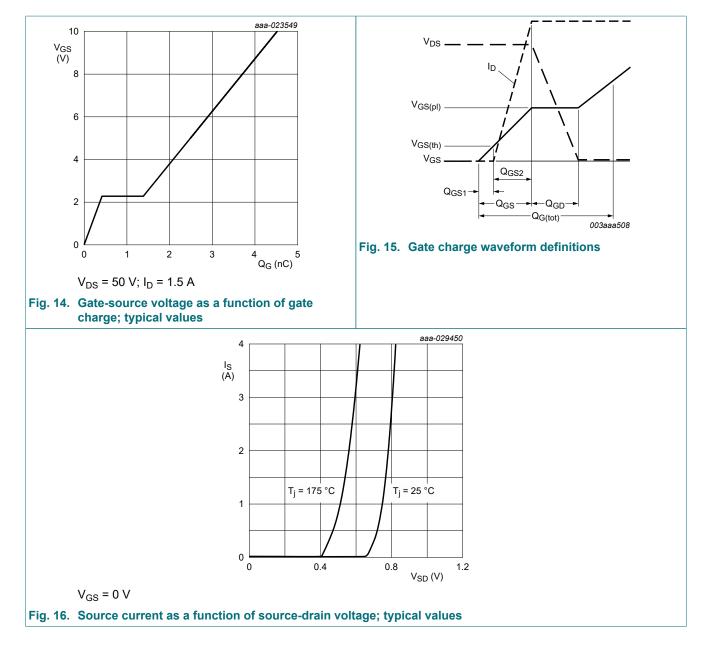
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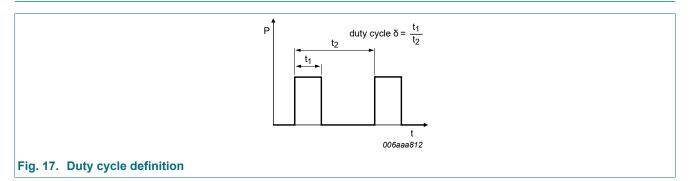
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11. Test information

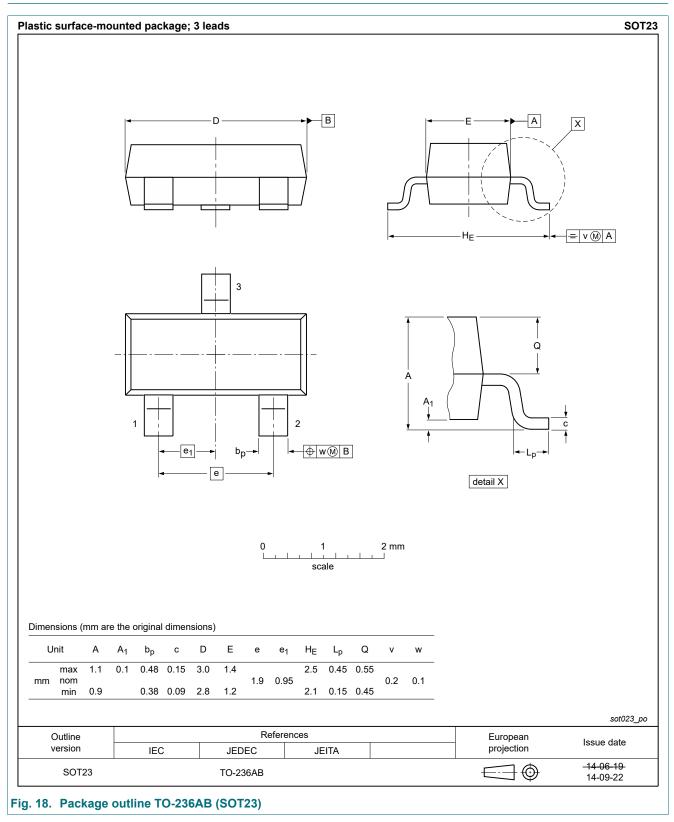


Quality information

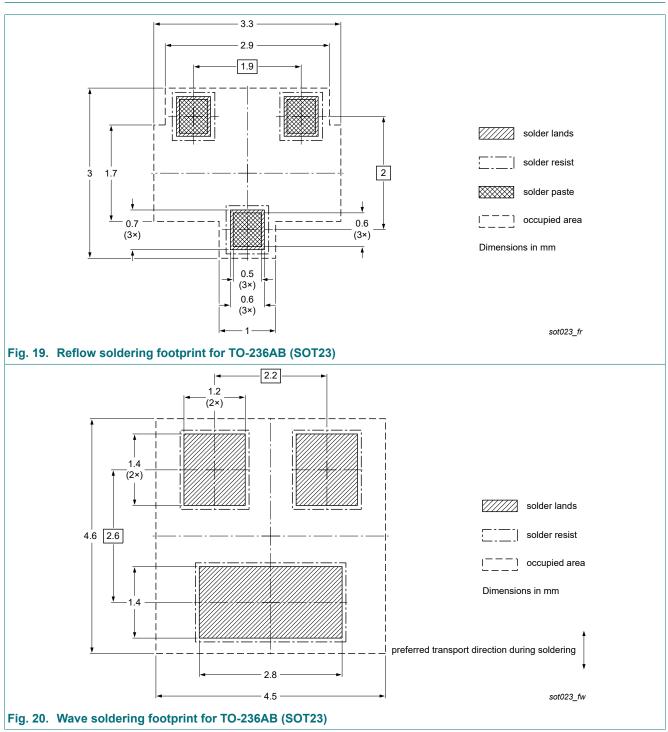
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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12. Package outline



13. Soldering



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14. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMV280ENEA v.2	20190411	Product data sheet	-	PMV280ENEA v.1
Modifications:	 Change from th °C 	ne temperature range T _j = 15	C to the extended te	emperature range T _j = 175
PMV280ENEA v.1	20161122	Product data sheet	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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